# **TEFT4300**

**Vishay Semiconductors** 



# Silicon NPN Phototransistor

#### **FEATURES**

- Package type: leaded
- Package form: T-1
- Dimensions (in mm): Ø 3
- High radiant sensitivity
- Daylight blocking filter matched with 940 nm emitters
- Fast response times
- Angle of half sensitivity:  $\varphi = \pm 30^{\circ}$
- · Package matched with IR emitter series TSUS4300 and TSAL4400
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### APPLICATIONS

- Optical switches
- · Counters and sorters
- Interrupters
- Encoders
- Position sensors

### 

DESCRIPTION

950 nm IR emitters.

| PRODUCT SUMMARY |                      |         |                       |  |
|-----------------|----------------------|---------|-----------------------|--|
| COMPONENT       | I <sub>ca</sub> (mA) | φ (deg) | λ <sub>0.5</sub> (nm) |  |
| TEFT4300        | 3.2                  | ± 30    | 875 to 1000           |  |

#### Note

Test condition see table "Basic Characteristics"

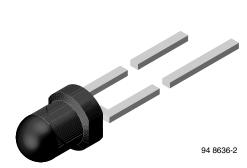
| ORDERING INFORMATION |                   |                              |              |  |
|----------------------|-------------------|------------------------------|--------------|--|
| ORDERING CODE        | PACKAGING REMARKS |                              | PACKAGE FORM |  |
| TEFT4300             | Bulk              | MOQ: 5000 pcs, 5000 pcs/bulk | T-1          |  |

#### Note

MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS (Tamb = 25 °C, unless otherwise specified) |  |                   |             |      |  |
|---|--|-------------------|-------------|------|--|
| PARAMETER   | TEST CONDITION                               | SYMBOL            | VALUE       | UNIT |  |
| Collector emitter voltage   |  | V <sub>CEO</sub>  | 70          | V    |  |
| Emitter collector voltage   |  | V <sub>ECO</sub>  | 5           | V    |  |
| Collector current   |  | Ι <sub>C</sub>    | 50          | mA   |  |
| Collector peak current  | $t_p/T = 0.5, t_p \le 10 \text{ ms}$         | I <sub>CM</sub>   | 100         | mA   |  |
| Power dissipation   | T <sub>amb</sub> ≤ 55 °C                     | Pv                | 100         | mW   |  |
| Junction temperature  |  | Tj                | 100         | °C   |  |
| Operating temperature range   |  | T <sub>amb</sub>  | -40 to +100 | °C   |  |
| Storage temperature range   |  | T <sub>stg</sub>  | -40 to +100 | °C   |  |
| Soldering temperature   | $t \le 3$ s, 2 mm from case                  | T <sub>sd</sub>   | 260         | °C   |  |
| Thermal resistance junction/ambient                                 | Connected with Cu wire, 0.14 mm <sup>2</sup> | R <sub>thJA</sub> | 450         | K/W  |  |





TEFT4300 is a silicon NPN phototransistor with high radiant

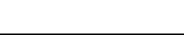
sensitivity in black, T-1 plastic package with daylight

blocking filter. Filter bandwidth is matched with 900 nm to

RoHS COMPLIANT HALOGEN

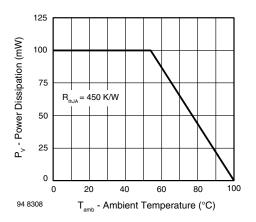
FREE <u>GREEN</u> (5-2008)





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www.vishay.com

Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

| <b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                      |      |             |      |      |
|---|---|----------------------|------|-------------|------|------|
| PARAMETER   | TEST CONDITION  | SYMBOL               | MIN. | TYP.        | MAX. | UNIT |
| Collector emitter breakdown voltage   | I <sub>C</sub> = 1 mA   | V <sub>(BR)CEO</sub> | 70   |             |      | V    |
| Collector emitter dark current  | $V_{CE} = 20 V, E = 0$  | I <sub>CEO</sub>     |      | 1           | 200  | nA   |
| Collector emitter capacitance   | $V_{CE} = 5 V, f = 1 MHz, E = 0$  | C <sub>CEO</sub>     |      | 3           |      | pF   |
| Collector light current   | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $V_{CE} = 5 \text{ V}$ | I <sub>ca</sub>      | 0.8  | 3.2         |      | mA   |
| Angle of half sensitivity   |   | φ                    |      | ± 30        |      | deg  |
| Wavelength of peak sensitivity  |   | λρ                   |      | 925         |      | nm   |
| Range of spectral bandwidth   |   | λ <sub>0.5</sub>     |      | 875 to 1000 |      | nm   |
| Collector emitter saturation voltage  | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $I_C = 0.1 \text{ mA}$ | V <sub>CEsat</sub>   |      |             | 0.3  | V    |
| Turn-on time  | $V_{S}$ = 5 V, $I_{C}$ = 5 mA, $R_{L}$ = 100 $\Omega$                           | t <sub>on</sub>      |      | 2           |      | μs   |
| Turn-off time   | $V_{S}$ = 5 V, $I_{C}$ = 5 mA, $R_{L}$ = 100 $\Omega$                           | t <sub>off</sub>     |      | 2.3         |      | μs   |
| Cut-off frequency   | $V_{S}$ = 5 V, $I_{C}$ = 5 mA, $R_{L}$ = 100 $\Omega$                           | f <sub>c</sub>       |      | 180         |      | kHz  |

#### BASIC CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

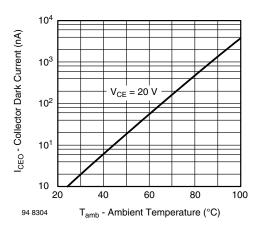


Fig. 2 - Collector Dark Current vs. Ambient Temperature

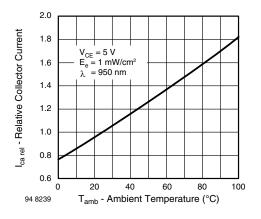


Fig. 3 - Relative Collector Current vs. Ambient Temperature

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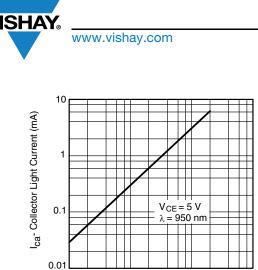


Fig. 4 - Collector Light Current vs. Irradiance

Ee - Irradiance(mW/cm<sup>2</sup>)

1

10

0.1

0.01

94 8302

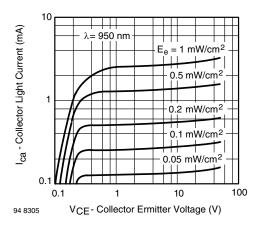


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

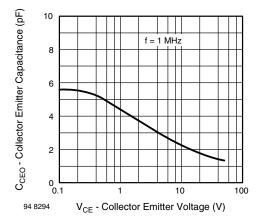


Fig. 6 - Collector Emitter Capacitance vs. Collector Emitter Voltage

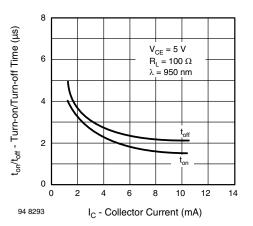


Fig. 7 - Turn-on/Turn-off Time vs. Collector Current

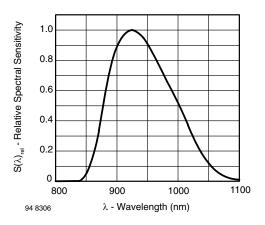


Fig. 8 - Relative Spectral Sensitivity vs. Wavelength

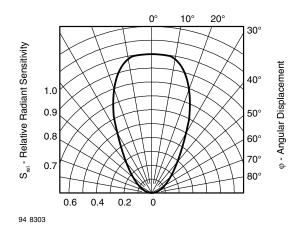


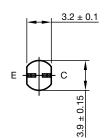
Fig. 9 - Relative Radiant Sensitivity vs. Angular Displacement

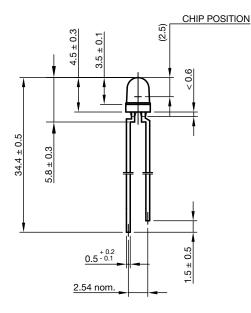
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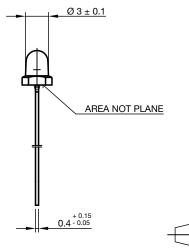


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#### **PACKAGE DIMENSIONS** in millimeters









technical drawings according to DIN specifications

Drawing-No.: 6.544-5269.01-4 Issue: 6; 28.07.14

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